MN39260FH

4.5 mm (type-1/4) 810k-pixel CCD Area Image Sensor

■ Overview

The MN39260FH is a 4.5 mm (type-1/4) interline transfer CCD (IT-CCD) solid state image sensor device.

This device uses photodiodes in the optoelectric conversion section and CCDs for signal readout. The electronic shutter function has made an exposure time of 1/10000 seconds possible. Further, this device has the features of high sensitivity, low noise, broad dynamic range, and low smear.

This device has a total of $802\,579$ pixels (1 007 horizontal $\times\,797$ vertical) and provides stable and clear images with a resolution of 600 horizontal TV-lines and 420 vertical TV-lines.

Part Number	Size	System	Color or B/W
MN39260FH	4.5 mm (type-1/4)	PAL	Color

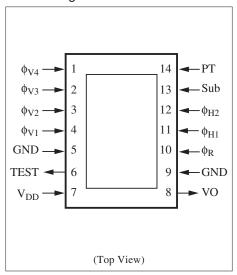
Features

- Effective pixel number 962 (horizontal) × 774 (vertical)
- High sensitivity
- Broad dynamic range
- Low smear
- Electronic shutter

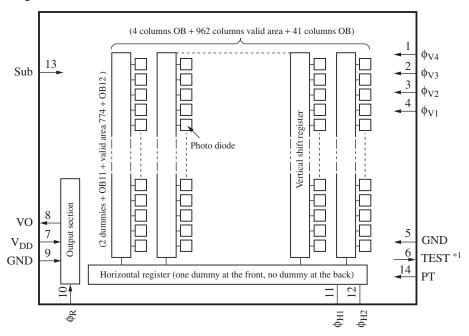
Applications

- Camcorders
- FA, OA cameras

■ Pin Assignments



■ Block Diagram



*1 : TEST pin must be left open, because the pin outputs CCD internal bias voltage.

■ Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	φ _{V4}	Vertical shift register clock pulse 4	8	VO	Video output
2	φ _{V3}	Vertical shift register clock pulse 3	9	GND	GND
3	φ _{V2}	Vertical shift register clock pulse 2	10	φ _R	Reset pulse (RG)
4	φ _{V1}	Vertical shift register clock pulse 1	11	ϕ_{H1}	Horizontal register clock pulse 1
5	GND	GND	12	ϕ_{H2}	Horizontal register clock pulse 2
6	TEST	TEST pin (OPEN) *1	13	Sub	Substrate
7	V_{DD}	Power supply	14	PT	P-well for protection circuit

Note) *1: TEST pin must be left open, because the pin outputs CCD internal bias voltage.

■ Device Parameter (H × V)

Parameter	Value	Unit
Pixel number *1	962 × 774	pixel
Image sensing block dimension	3.7037×2.7090	mm ²
Pixel dimension	3.85×3.50	μm ²

Note) *1: OB columns are not included.

■ Absolute Maximum Ratings and Operating Conditions

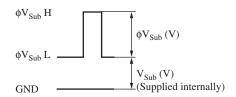
Parameter		Absolute maximum rating		Operating condition			T
		Lower limit	Upper limit	Min	Тур	Max	Unit
V_{DD}		- 0.2	18	14.5	15.0	15.5	V
V _{PT} *3, 4		-10.0	0.2	-7.5	-7.0	-6.5	V
GND		(Referenc	e voltage)	_	0	_	V
$V_{\phi R}$	High-Low	_	8	3.0	3.3	3.6	V
	Bias	(Supplied internally)					V
$V_{\phi H1}$	High	_	8	3.0	3.3	3.6	V
	Low	- 0.2	_	- 0.2	0	0.2	V
$V_{\phi H2}$	High	_	8	3.0	3.3	3.6	V
	Low	- 0.2	_	- 0.2	0	0.2	V
V _{Sub} *2			(S	upplied internally)			V
ϕV_{Sub}^{*1}		- 0.2	35	21.0	22.0	23.0	V
$V_{\phi V1}$ *3, 4	High	_	18	14.5	15.0	15.5	V
	Middle	_	_	- 0.05	0	0.05	V
	Low	-9	_	-7.5	-7.0	-6.5	V
$V_{\phi V2}^{\ *3,\ 4}$	Middle	_	15	- 0.05	0	0.05	V
	Low	-9	_	-7.5	-7.0	-6.5	V
V _{\phiV3} *3, 4	High	_	18	14.5	15.0	15.5	V
	Middle	_	_	- 0.05	0	0.05	V
	Low	-9	_	-7.5	-7.0	-6.5	V
$V_{\phi V4}^{\ *3,\ 4}$	Middle	_	15	- 0.05	0	0.05	V
	Low	-9	_	-7.5	-7.0	-6.5	V
Operating temperature		-10	60	_	25	_	°C
Storage temperature		-30	80	_	_	_	°C

■ Absolute Maximum Ratings and Operating Conditions (continued)

Note) 1. Standard photo detecting condition

Standard photo detecting condition stands for detecting image with a light source of color temperature of 2856K, luminance of 1050 cd/m², and using a color temperature conversion filter LB-40 (HOYA), infrared cut filter CAW-500S with thickness 2.5 mm for a light path and with F8 lens aperture. The quantity of the incidental light to a photo-detecting surface under the above condition is defined as the standard quantity of light.

2. $*1: V_{Sub}$ when using electronic shutter function



* \$\phi Sub pulse generates once every 1 V period.

- *2: V_{Sub} supplied internally is the voltage suppressing the blooming generation at $\times 500$ light quantity relative to the standard light quantity.
- *3: Relation between V_{PT} and $V_{\phi VL}$

Set V_{PT} under the following condition against VL of a vertical transfer clock waveform.

$$V_{PT} \le VL \ (V_{\phi V1L} \ to \ V_{\phi V4L})$$

*4: Absolute maximum ratings $-0.2 < V_{\phi V} - V_{PT} < 24.5 \text{ (V)}$

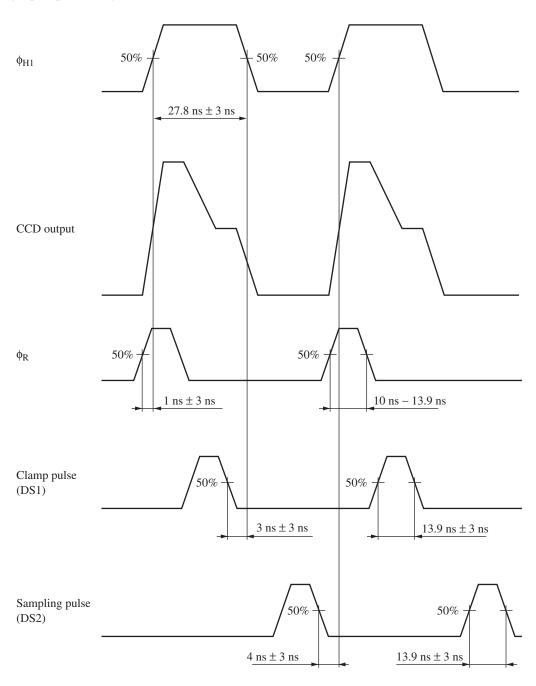
■ Optical Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Carrier saturation output	Sc	J chart	500	_	_	mV
Sensitivity	So	J chart F1.4, 1/32 ND	80	110	_	mV
Vertical smear	Sm	1/10 V chart, F1.4	_	_	0.01	%

Note) The above-mentioned characteristics are the values on driving the device for the imaging stabilizer mode (1/60 seconds accumulation).

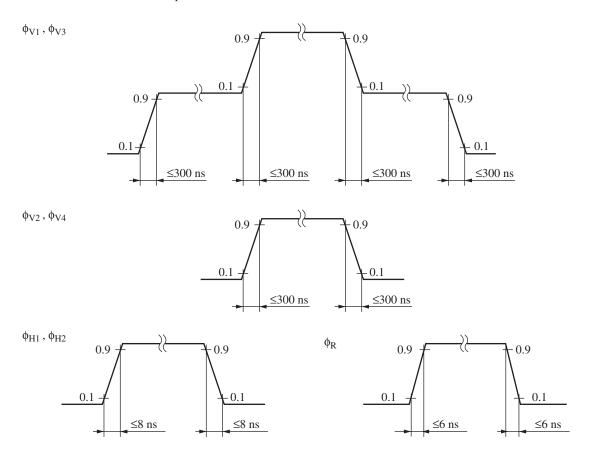
■ Timing Diagram

• High speed pulse timing

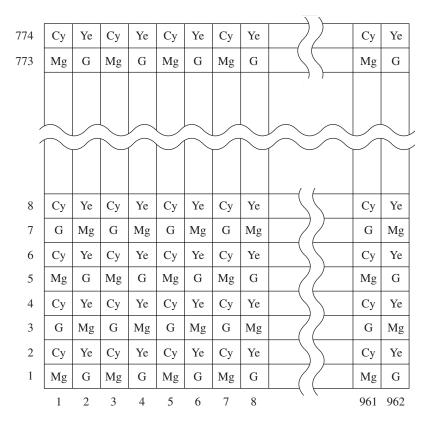


■ Timing Diagram (continued)

• Rise time and fall time of each pulse

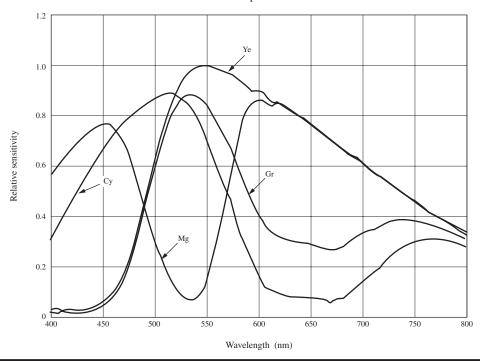


■ Color Filter Arrays on CCD



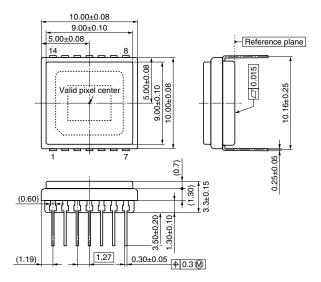
■ Graph of Characteristics

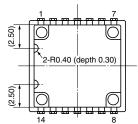
CCD color filter spectral characteristics



■ Package Dimensions (unit: mm)

• WDIP014-P-0400H





- 1. The center of the package is equal to the center of the effective pixel area.
- 2. The rotation angle of the effective pixel area: up to ± 1.0 degree
- 3. The distance from the bottom face of the package to the surface of the effective pixel area: 1.41 mm \pm 0.1 mm
- 4. The tilt of the effective pixel area for the bottom face of the package: up to 25 μm
- 5. Thickness of seal glass is 0.7 mm \pm 0.1 mm, and the refractive index is 1.50.
- 6. Package weight: 0.55 g (typ.)

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